



SANYO Semiconductors

DATA SHEET

MCH3145 / MCH3245

 — PNP / NPN Epitaxial Planar Silicon Transistors

DC / DC Converter Applications

Applications

- Relay drivers, lamp drivers, motor drivers, flash.

Features

- Adoption of MBIT processes.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Ultrasmall package permitting applied sets to be small and slim (mounting height : 0.85mm).
- High allowable power dissipation.

Specifications () : MCH3145

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		(-50)80	V
Collector-to-Emitter Voltage	V _{CES}		(-50)80	V
Collector-to-Emitter Voltage	V _{CEO}		(-)50	V
Emitter-to-Base Voltage	V _{EBO}		(-)6	V
Collector Current	I _C		(-)2	A
Collector Current (Pulse)	I _{CP}		(-)4	A
Base Current	I _B		(-)400	mA
Collector Dissipation	P _C	Mounted on a ceramic board (600mm ² X0.8mm)	0.8	W
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CBO}	V _{CB} =(-)40V, I _E =0			(-)1	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)4V, I _C =0			(-)1	μA
DC Current Gain	h _{FE}	V _{CE} =(-)2V, I _C =(-)100mA	200		560	
Gain-Bandwidth Product	f _T	V _{CE} =(-)10V, I _C =(-)300mA		420		MHz
Output Capacitance	C _{ob}	V _{CB} =(-)10V, f=1MHz		(16)8		pF

Marking : MCH3145 : AN, MCH3245 : CS

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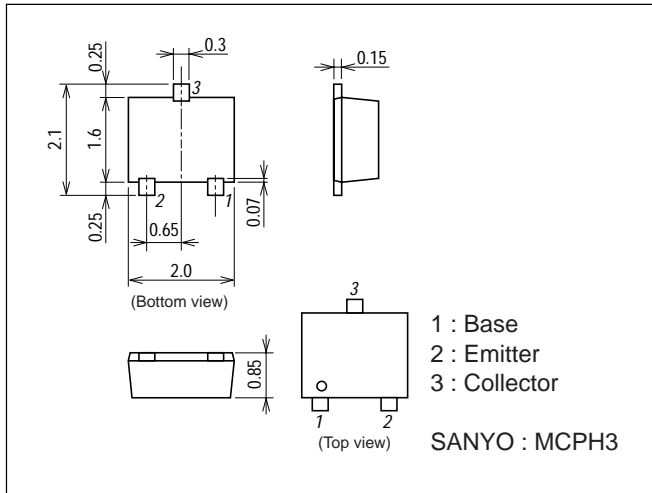
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = (-)1A, I_B = (-)50mA$		(-165)130	(-330)260	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = (-)1A, I_B = (-)50mA$		(-)0.9	(-)1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = (-)10\mu A, I_E = 0$	(-50)80			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CES}$	$I_C = (-)100\mu A, R_{BE} = 0$	(-50)80			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = (-)1mA, R_{BE} = \infty$	(-)50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = (-)10\mu A, I_C = 0$	(-)6			V
Turn-ON Time	t_{on}	See specified Test Circuit.		(35)35		ns
Storage Time	t_{stg}	See specified Test Circuit.		(200)330		ns
Fall Time	t_f	See specified Test Circuit.		(24)40		ns

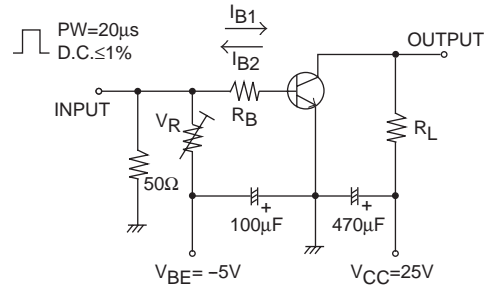
Package Dimensions

unit : mm

2194A

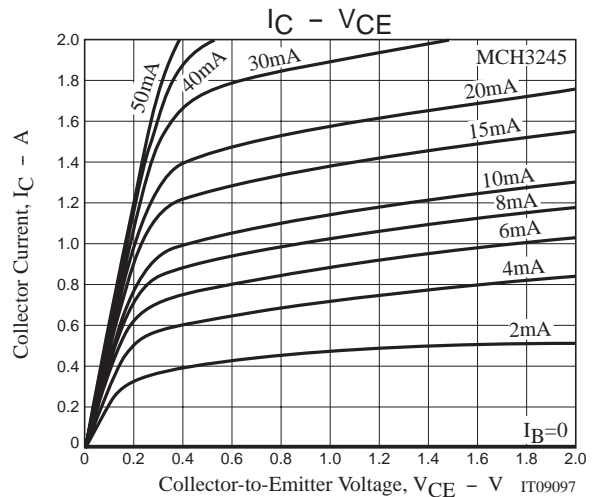
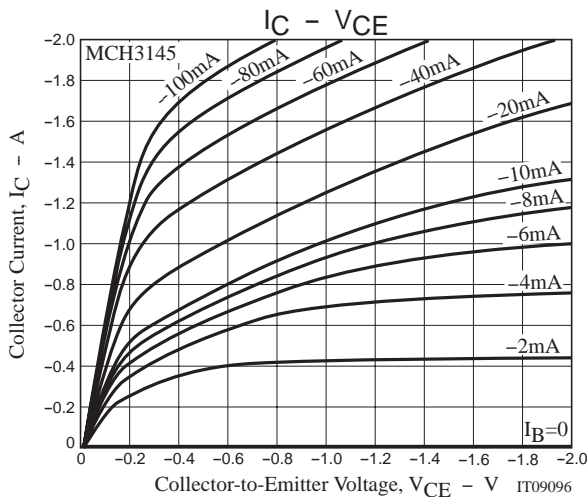


Switching Time Test Circuit

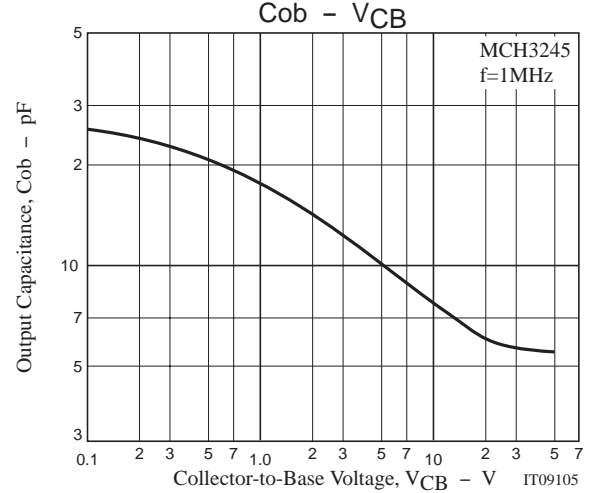
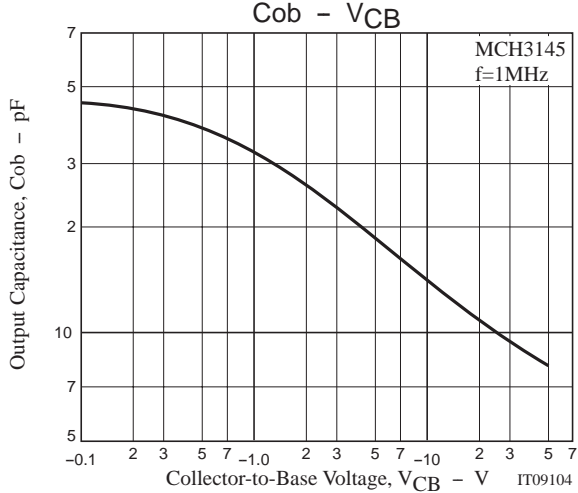
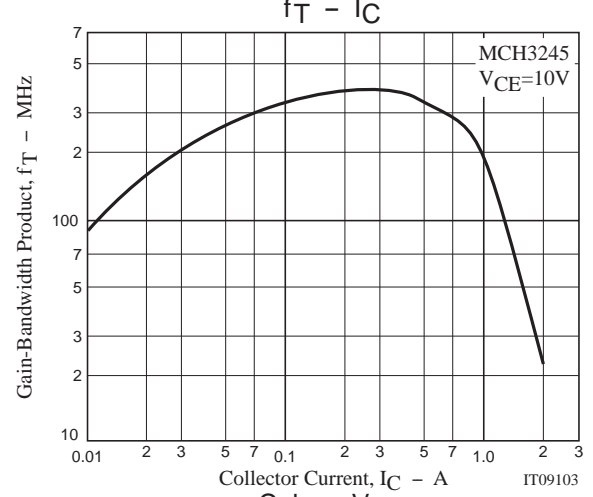
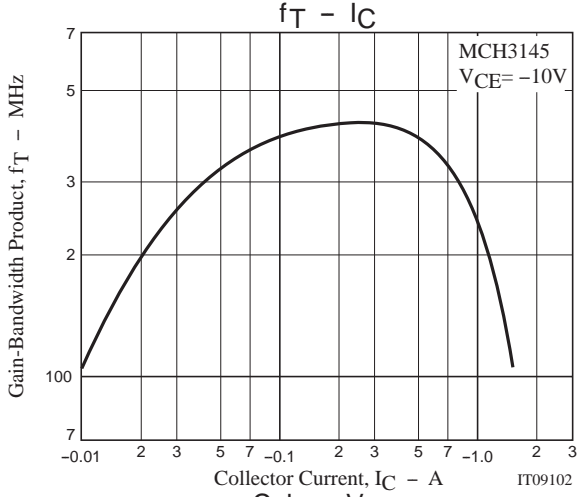
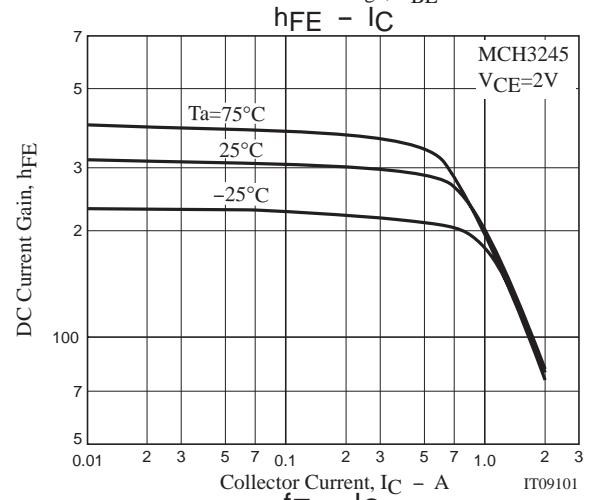
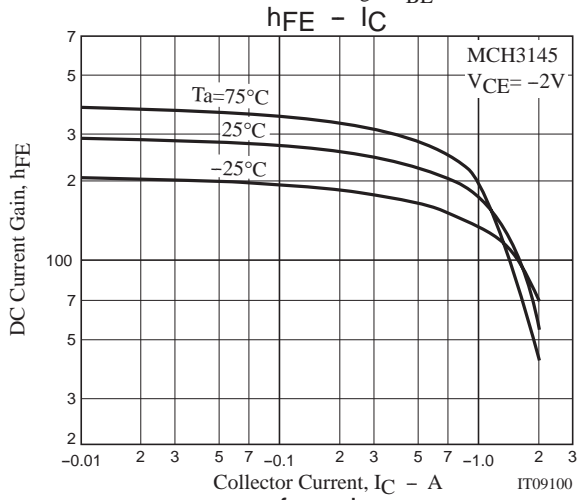
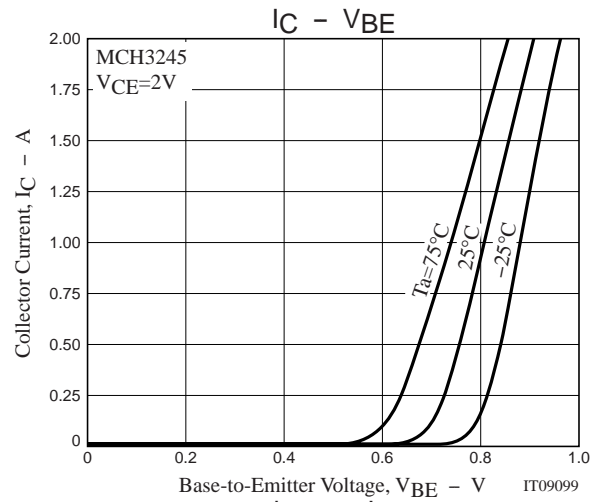
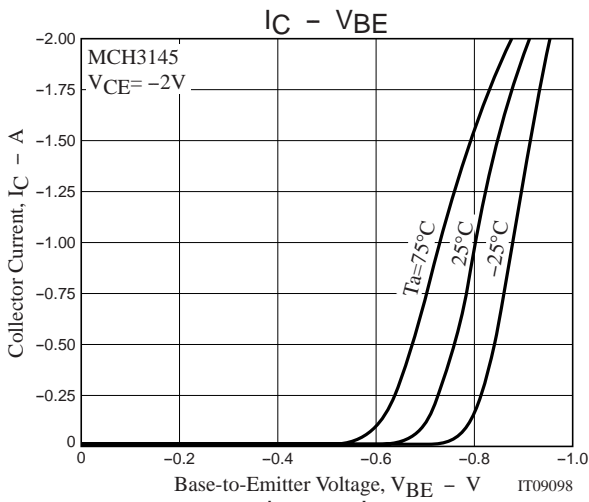


$$I_C = 10I_{B1} = -10I_{B2} = 0.7A$$

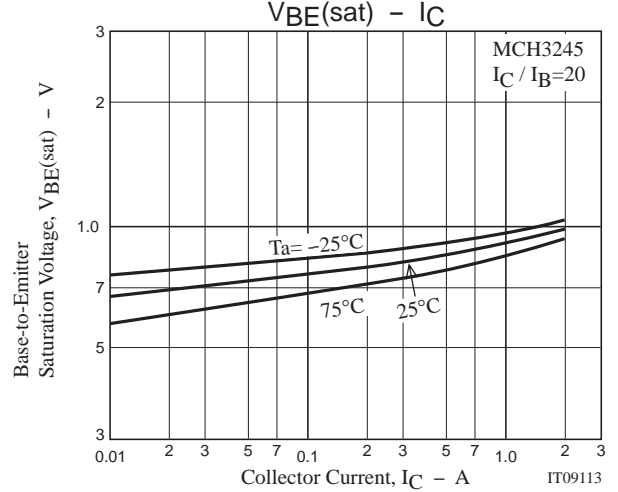
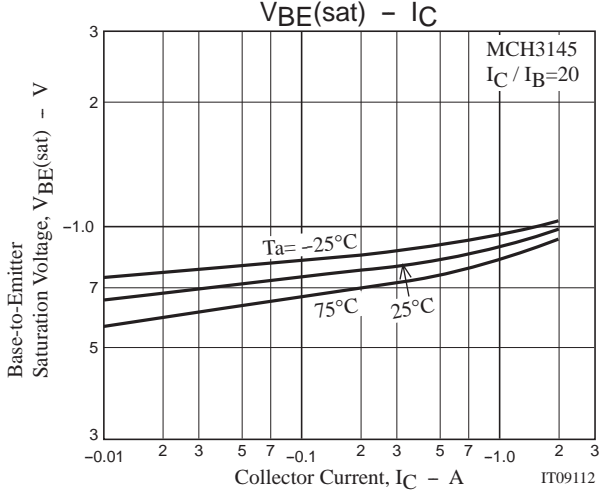
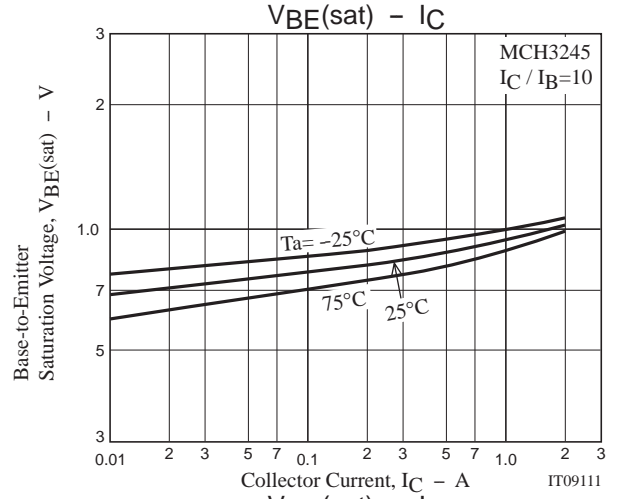
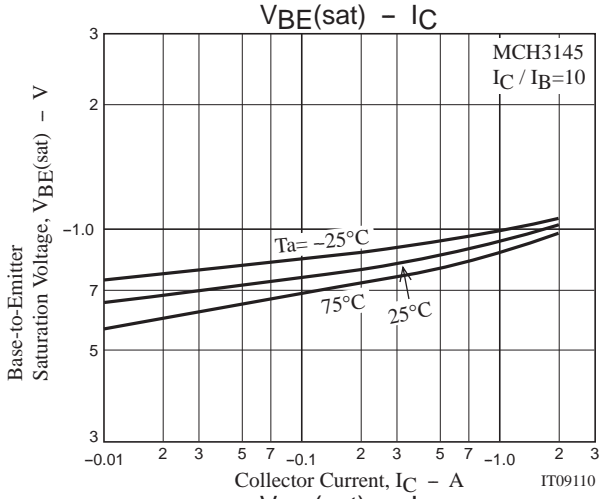
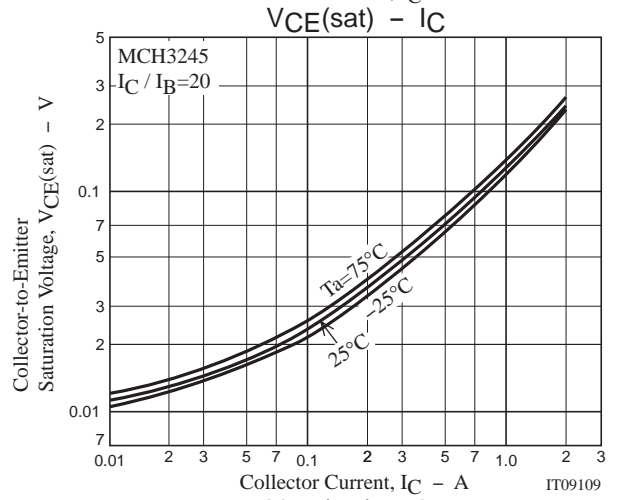
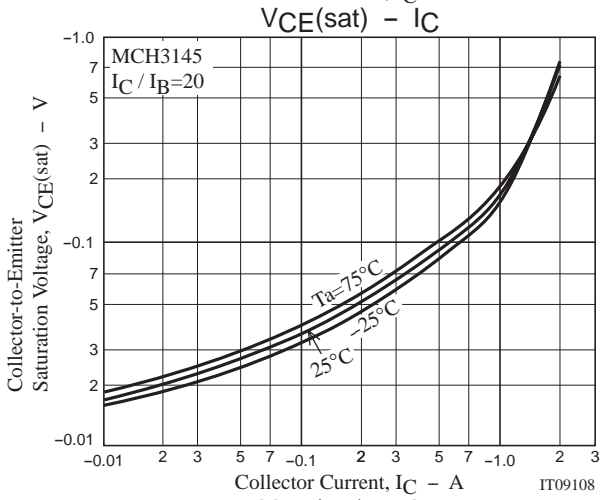
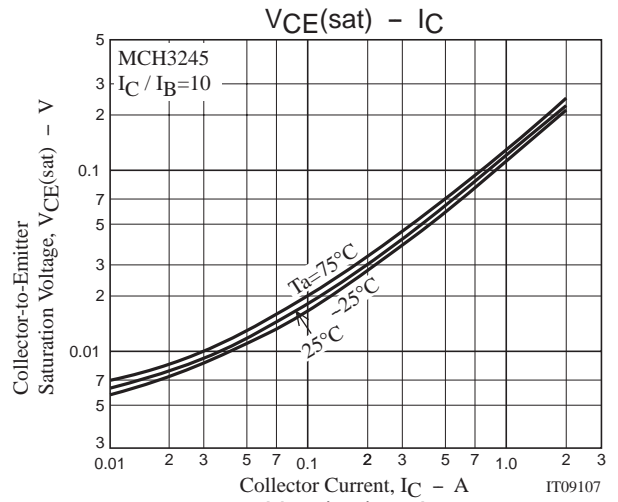
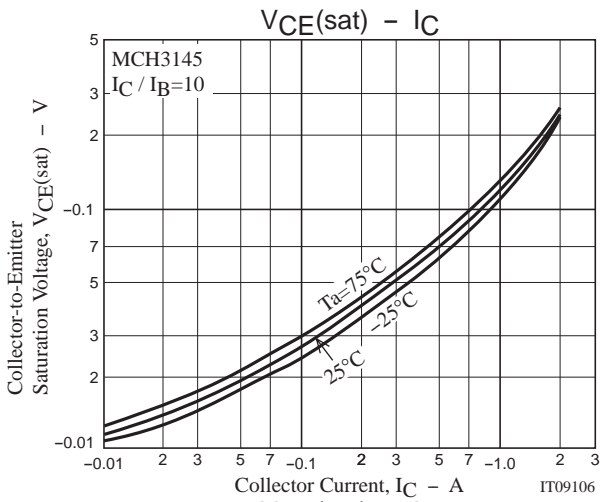
For PNP, the polarity is reversed.



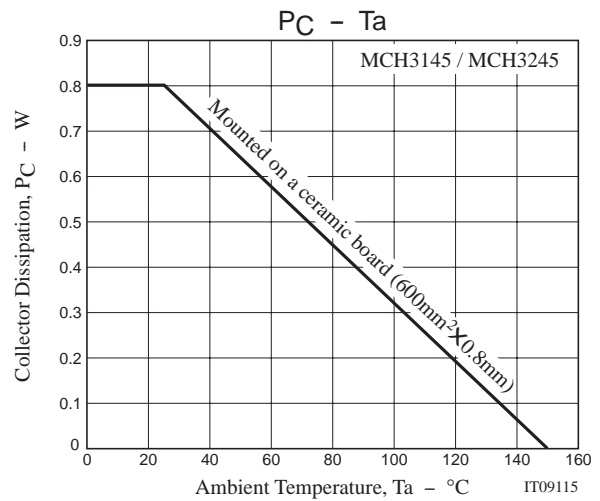
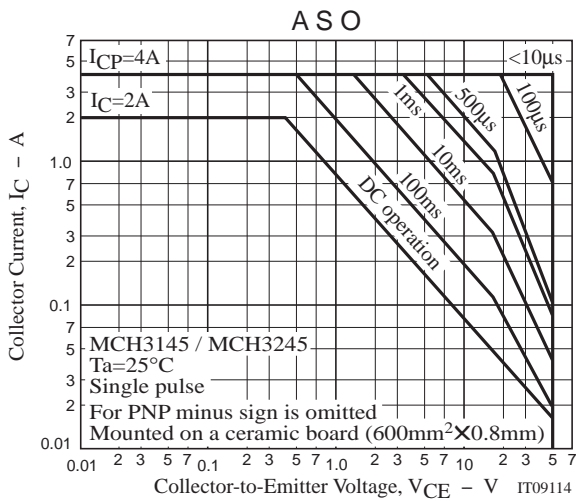
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